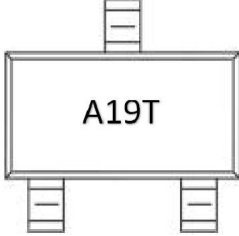
	<p>TrenchFET Power MOSFET Exceptional on-resistance and maximum DC current capability High dense cell design for extremely low $R_{DS(on)}$</p> <div style="display: flex; justify-content: space-around; align-items: center;"> A G  </div>
---	---

(B)D	D () A	D
- 30 V	60m V	- 4. 1A
	65m V	
	100m V	

(=25)

Parameter	Symbol	Value	Unit



FE E EC CA C A AC E C E C (= 25)						
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
D						
D -						
:						

C :

